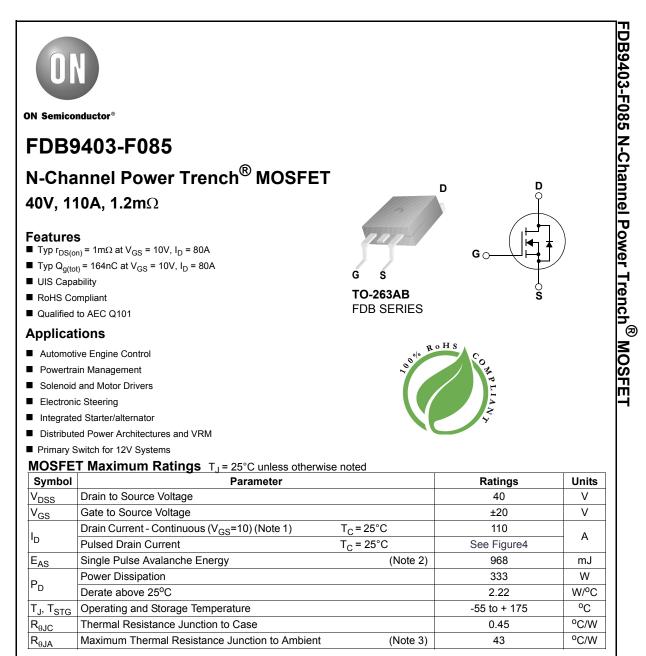
**ON Semiconductor** 

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# Onsemi

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## Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDB9403	FDB9403-F085	TO-263AB	330mm	24mm	800 units

Notes:

1. Current is limited by bondwire configuration. Please see ON Semiconductor AN 9757-1 for details on test method.

2: Starting  $T_J = 25^{\circ}$ C, L = 0.47mH,  $I_{AS} = 64A$ ,  $V_{DD} = 40V$  during inductor charging and  $V_{DD} = 0V$  during time in avalanche.

3:  $R_{\theta JA}$  is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins.  $R_{\theta JC}$  is guaranteed by design while  $R_{\theta JA}$  is determined by the user's board design. The maximum rating presented here is based on mounting on a 1 in<sup>2</sup> pad of 2oz copper.

Symbol	Parameter	Test	Conditions	Min	Тур	Мах	Units
Off Cha	racteristics						
B <sub>VDSS</sub>	Drain to Source Breakdown Voltage	I <sub>D</sub> = 250μA, V <sub>GS</sub> = 0V		40	-	-	V
I <sub>DSS</sub>	Drain to Source Leakage Current	V <sub>DS</sub> =40V,	T <sub>J</sub> = 25 <sup>o</sup> C	-	-	1	μA
		$V_{GS} = 0V$	$T_J = 175^{\circ}C(Note 4)$	-	-	1	mA
I <sub>GSS</sub>	Gate to Source Leakage Current	$V_{GS} = \pm 20V$		-	-	±100	nA
V <sub>GS(th)</sub>	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_D$ $I_D = 80A,$	T <sub>J</sub> = 25 <sup>o</sup> C	-	1.0	1.2	mΩ
r <sub>DS(on)</sub>	Drain to Source On Resistance			-	-		
- (- )		V <sub>GS</sub> = 10V	$T_J = 175^{\circ}C(Note 4)$	-	1.63	1.96	mΩ
Dynami <sub>C<sub>iss</sub></sub>	c Characteristics				12700	_	pF
	Output Capacitance	V <sub>DS</sub> = 25V, V <sub>GS</sub> = 0V, f = 1MHz f = 1MHz			3195	-	pF
C <sub>oss</sub>	Reverse Transfer Capacitance				493	-	pr
C <sub>rss</sub>	Gate Resistance				2.9		Ω
R <sub>g</sub>	Total Gate Charge at 10V			-	2.9	- 213	nC
Q <sub>g(ToT)</sub>	•	$V_{GS} = 0 \text{ to } 10^{\circ}$ $V_{GS} = 0 \text{ to } 2^{\circ}$		-	23	213 30	-
Q <sub>g(th)</sub>	Threshold Gate Charge						nC

# **Switching Characteristics**

Gate to Source Gate Charge

Gate to Drain "Miller" Charge

t <sub>on</sub>	Turn-On Time		-	-	56	ns
t <sub>d(on)</sub>	Turn-On Delay Time		-	16	-	ns
t <sub>r</sub>	Rise Time	V <sub>DD</sub> = 20V, I <sub>D</sub> = 80A,	-	19.5	-	ns
t <sub>d(off)</sub>	Turn-Off Delay Time	$V_{DD}$ = 20V, I <sub>D</sub> = 80A, V <sub>GS</sub> = 10V, R <sub>GS</sub> = 1.5Ω	-	61	-	ns
t <sub>f</sub>	Fall Time		-	46	-	ns
t <sub>off</sub>	Turn-Off Time		-	-	171	ns

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59

25

-

-

nC

nC

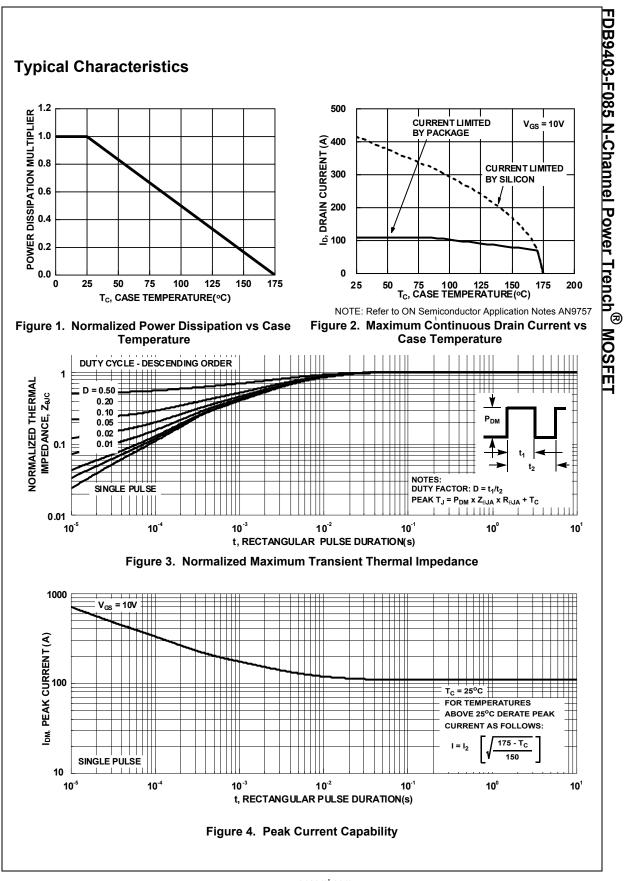
# **Drain-Source Diode Characteristics**

V <sub>SD</sub>		I <sub>SD</sub> = 35A, V <sub>GS</sub> = 0V	-	-	0.85	V
		I <sub>SD</sub> = 15A, V <sub>GS</sub> = 0V	-	-	0.80	V
Trr	Reverse Recovery Time	I <sub>F</sub> = 80A, dI <sub>SD</sub> /dt = 100A/μs	-	96	125	ns
Q <sub>rr</sub>	Reverse Recovery Charge		-	149	194	nC

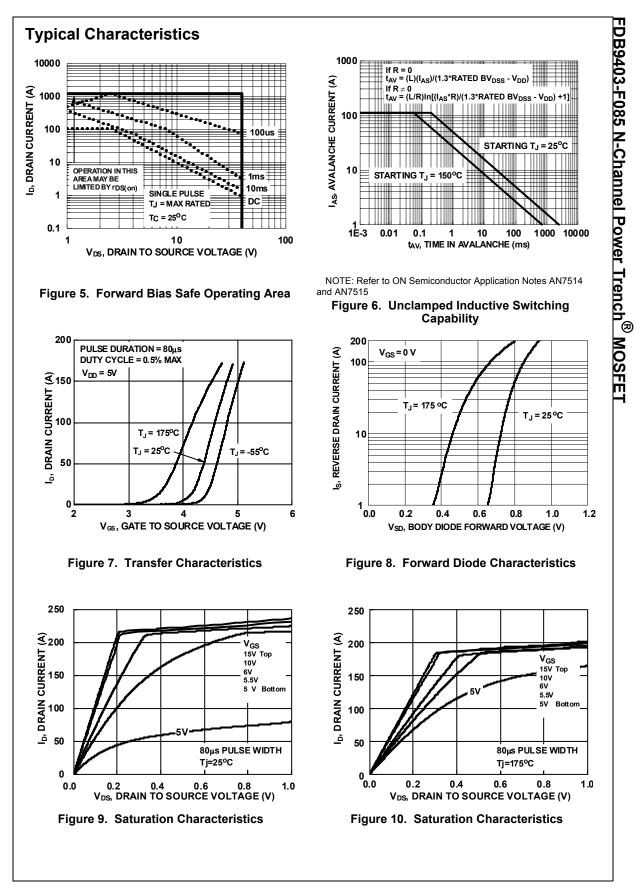
Notes:

Q<sub>gs</sub> Q<sub>gd</sub>

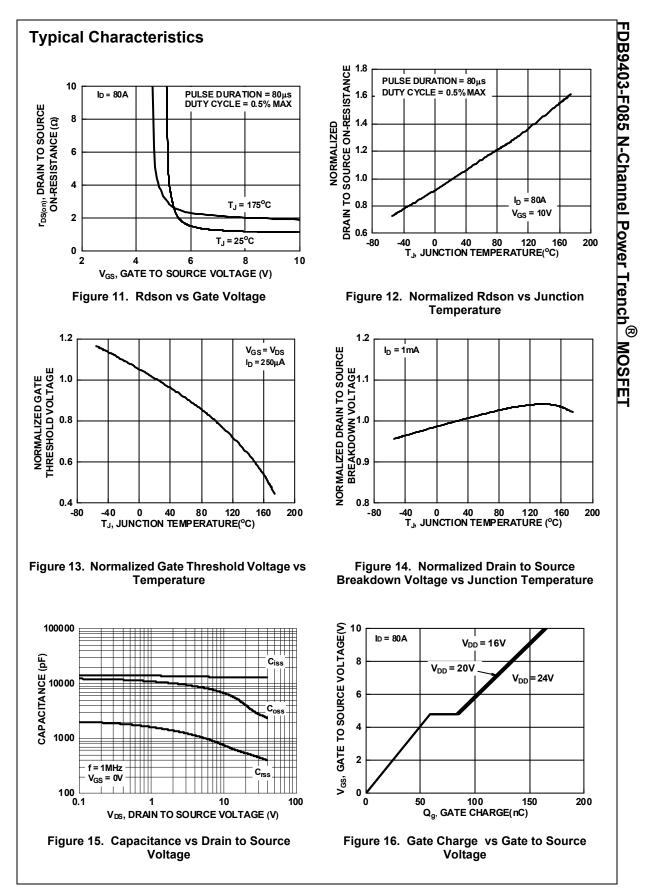
4: The maximum value is specified by design at TJ = 175°C. Product is not tested to this condition in production.



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